BLF7G20L-90P; BLF7G20LS-90P Power LDMOS transistor Rev. 3 — 1 September 2015

AMPLEON

Product data sheet

Product profile 1.

1.1 General description

90 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz, designed for operation at 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit.

Mode of operation	f	I _{Dq}	V _{DS}	P _{L(AV)}	Gp	η_{D}	ACPR _{400k}	ACPR _{600k}	EVM _{rms}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)	(%)
CW	1805 to 1880	550	28	84	19	54	-	-	-
GSM EDGE	1805 to 1880	550	28	40	19.5	41	- 61	-74	2.5

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

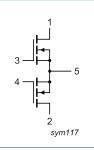
 RF power amplifiers for base stations and multi carrier applications in the frequency bands of 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

2. Pinning information

Table 2. Pinning

Pin Description Simplified outline Graphic symbol BLF7G20L-90P (SOT1121A) 1 drain1 2 drain2 3 gate1 4 gate2 5 source [1] 1 3 4		9			
1 drain1 2 drain2 3 gate1 4 gate2 5 source [1]	Pin	Description		Simplified outline	Graphic symbol
2 drain2 3 gate1 4 gate2 5 source [1]	BLF7G20L-9	90P (SOT1121A)			
2 drain2 3 gate1 4 gate2 5 source [1] 3 4	1	drain1			
4 gate2 5 source 11 3 4 5	2	drain2			1
4 gate2 5 source [1] 3 4	3	gate1			<u>,</u>
5 source 11 3 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4	4	gate2			5
'├── 2 sym117	5	source	<u>[1]</u>		4
2 sym117					' <u></u>
					2 sym117

BLF7G20LS-90P (SOT1121B)				
1	drain1			
2	drain2			
3	gate1			
4	gate2			
5	source		<u>[1]</u>	



3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLF7G20L-90P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A		
BLF7G20LS-90P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	18	Α
T _{stg}	storage temperature		-65	+150	°С
Tj	junction temperature		-	200	°C

^[1] Connected to flange.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 90 W	0.49	K/W

6. Characteristics

Table 6. Characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_{D} = 50 \text{ mA}$	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	8.2	9.5	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	200	nΑ
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 2.5 \text{ A}$	-	3.8	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.75 \text{ A}$	-	0.28	-	Ω

7. Test information

Table 7. Application information

f = 1805 MHz to 1880 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 550 mA; T_{case} = 25 °C; 2 sections combined unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
Mode of o	Mode of operation: GSM EDGE; P _{L(AV)} = 40 W							
Gp	power gain		18.3	19.5	-	dB		
RLin	input return loss		-	-15	-8	dB		
η_{D}	drain efficiency		38	41	-	%		
ACPR _{400k}	adjacent channel power ratio (400 kHz)		-	– 61	– 58	dBc		
ACPR _{600k}	adjacent channel power ratio (600 kHz)		-	-7 4	- 70.5	dBc		
EVM_{rms}	RMS EDGE signal distortion error		-	2.5	3.8	%		
EVM_M	peak EDGE signal distortion error		-	8	12.5	%		
Mode of o	peration: CW; P _{L(AV)} = 84 W							
Gp	power gain		17.8	19	-	dB		
η_{D}	drain efficiency		51	54	-	%		

7.1 Ruggedness in class-AB operation

The BLF7G20L-90P and BLF7G20LS-90P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

 $V_{DS} = 28 \text{ V; } I_{Dq} = 550 \text{ mA; } P_L = 90 \text{ W (CW), } f = 1805 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 40 \text{ W (CW, half device), } f = 2110 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 55 \text{ W (CW pulse, } 10 \text{ %, } 100 \text{ } \mu\text{s, halve device),} \\ f = 1427 \text{ MHz.}$

7.2 One-tone CW

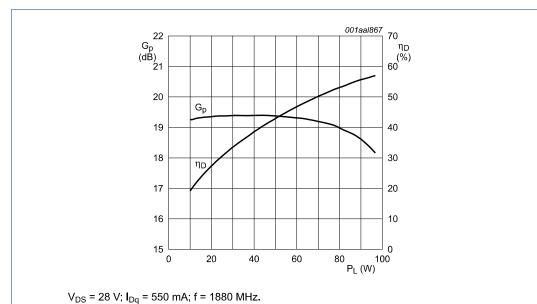


Fig 1. One-tone CW power gain and drain efficiency as function of load power; typical values

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7.3 Two-tone CW

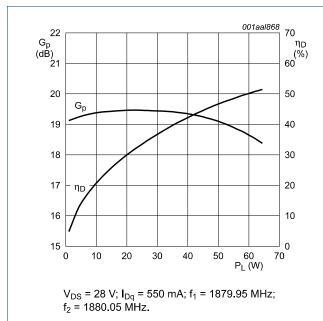


Fig 2. Two-tone CW power gain and drain efficiency as function of load power; typical values

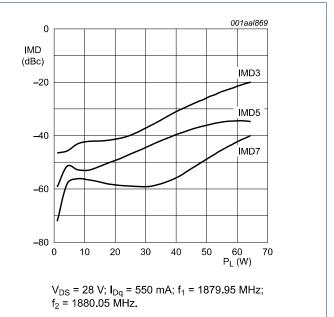


Fig 3. Two-tone CW intermodulation distortion as a function of load power; typical values

7.4 GSM EDGE

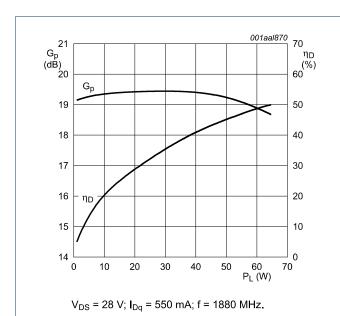
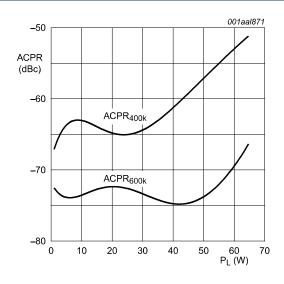
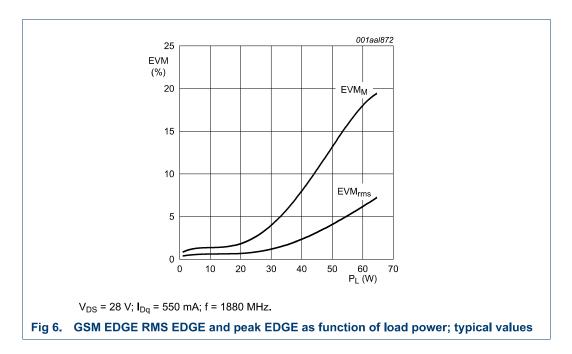


Fig 4. GSM EDGE power gain and drain efficiency as function of load power; typical values



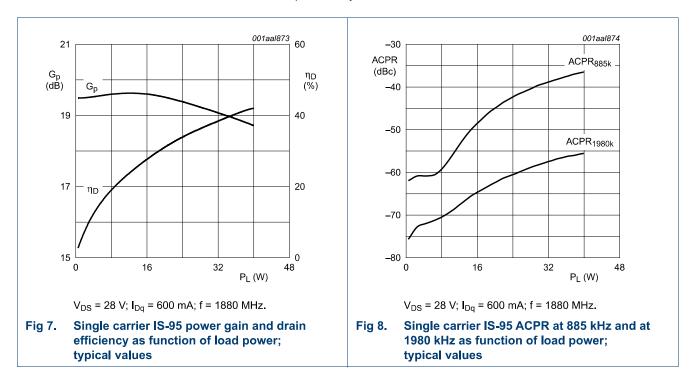
 V_{DS} = 28 V; I_{Dq} = 550 mA; f = 1880 MHz.

Fig 5. GSM EDGE ACPR at 400 kHz and at 600 kHz as function of load power; typical values



7.5 Single carrier IS-95

Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



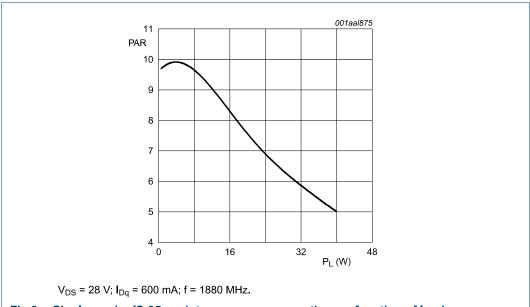


Fig 9. Single carrier IS-95 peak-to-average power ratio as a function of load power; typical values

7.6 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

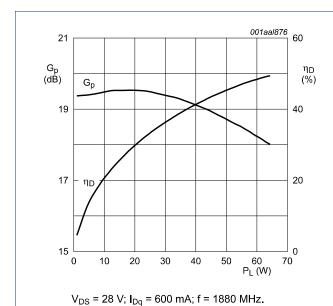
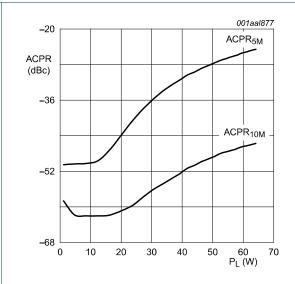


Fig 10. Single carrier W-CDMA power gain and drain efficiency as function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 600 mA; f = 1880 MHz.

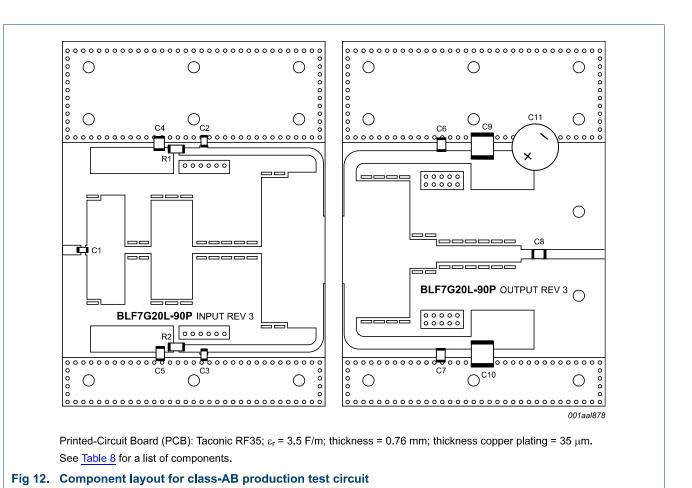
Fig 11. Single carrier W-CDMA ACPR at 5 MHz and at 10 MHz as function of load power; typical values

7.7 Test circuit

Table 8. List of components For test circuit see Figure 12.

Component	Description	Value	Remarks
C1, C2, C3	multilayer ceramic chip capacitor	24 pF	[1]
C4, C5	multilayer ceramic chip capacitor	4.7 μF	[2]
C6, C7, C8	multilayer ceramic chip capacitor	11 pF	[3]
C9, C10	multilayer ceramic chip capacitor	10 μF	[2]
C11	electrolytic capacitor	470 μF; 63 V	
R1, R2	SMD resistor	12 Ω	Philips 1206

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] TDK or capacitor of same quality.
- [3] American Technical Ceramics type 100B or capacitor of same quality.



7.8 Impedance information

Table 9. **Typical impedance**

Typical values valid for both section in parallel unless otherwise specified.

f	Z _S	Z _L
MHz	Ω	Ω
1800	1.0 – j3.3	2.8 – j2.7
1840	1.2 – j3.3	2.8 – j2.5
1880	1.1 – j3.4	2.7 – j2.4

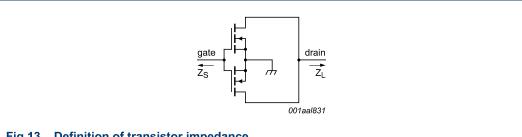


Fig 13. Definition of transistor impedance

8. Package outline

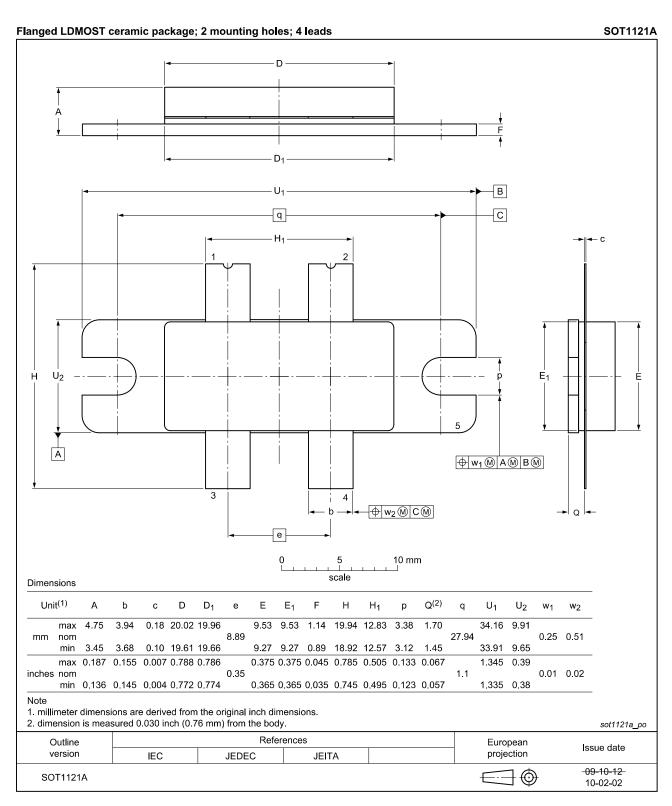


Fig 14. Package outline SOT1121A

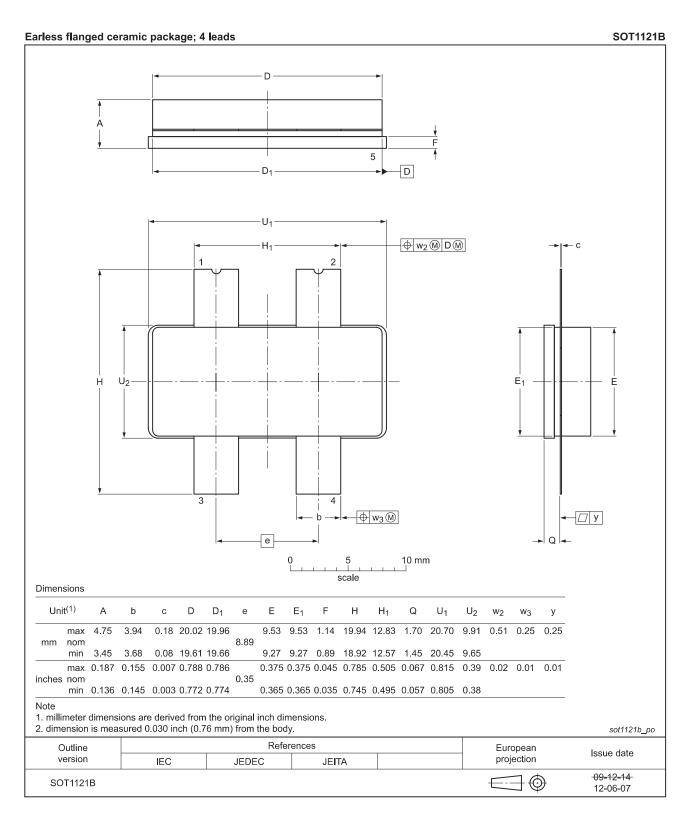


Fig 15. Package outline SOT1121B

9. Abbreviations

Table 10. Abbreviations

10010 101 710011	ovidations —
Acronym	Description
3GPP	3rd Generation Partnership Project
CW	Continuous Wave
CCDF	Complementary Cumulative Distribution Function
DPCH	Dedicated Physical Channel
EDGE	Enhanced Data rates for GSM Evolution
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF7G20L-90P_7G20LS-90P#3	20150901	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.2		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 					
BLF7G20L-90P_7G20LS-90P v.2	20111020	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.1		
BLF7G20L-90P_7G20LS-90P v.1	20100428	Product data sheet	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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